

BTW67 and BTW69 Series

STANDARD 50A SCRS

Table 1: Main Features

| Symbol | Value | Unit |
|------------------------------------|-------------|------|
| I _{T(RMS)} | 50 | Α |
| V _{DRM} /V _{RRM} | 600 to 1200 | V |
| I _{GT} | 80 | mA |

DESCRIPTION

Available in high power packages, the **BTW67** / **BTW69** Series is suitable in applications where power handling and power dissipation are critical, such as solid state relays, welding equipment, high power motor control.

Based on a clip assembly technology, they offer a superior performance in surge current handling capabilities.

Thanks to their internal ceramic pad, they provide high voltage insulation ($2500V_{RMS}$), complying with UL standards (file ref: E81734).

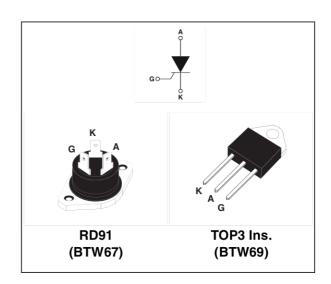


Table 2: Order Codes

| Part Numbers | Marking |
|--------------|----------|
| BTW67-xxx | BTW67xxx |
| BTW69-xxxRG | BTW69xxx |

Table 3: Absolute Ratings (limiting values)

| Symbol | Parameter | | | Value | Unit | |
|------------------------------------|-----------------------------------------------------------------------------------|--------------------------------|------------------------|-------|------------------|--|
| 1 | RMS on-state current | RD91 | $T_c = 70^{\circ}C$ | 50 | Α | |
| I _{T(RMS)} | (180° conduction angle) | TOP3 Ins. | T _c = 75°C | 50 | A | |
| ITs | Average on-state current | RD91 | T _c = 70°C | 00 | Α | |
| IT _(AV) | (180° conduction angle) | TOP3 Ins. | T _c = 75°C | 32 | A | |
| I | Nico was attitus as was a sale as at a summan | | T _i = 25°C | 610 | Α | |
| I _{TSM} | Non repetitive surge peak on-state current | $t_p = 10 \text{ ms}$ | | 580 | ^ | |
| l ² t | I^2t Value for fusing $T_j = 25$ | | | 1680 | A ² s | |
| dI/dt | Critical rate of rise of on-state current $I_G = 2$ x I_{GT} , $t_r \le 100$ ns | F = 60 Hz | T _j = 125°C | 50 | A/µs | |
| I _{GM} | Peak gate current $t_p = 20 \mu s$ $T_j = 125^{\circ} C$ | | T _j = 125°C | 8 | Α | |
| P _{G(AV)} | Average gate power dissipation | 1 | W | | | |
| T _{stg} T _j | Storage junction temperature range Operating junction temperature range | - 40 to + 150 - 40 to + 125 | °C | | | |
| V _{RGM} | Maximum peak reverse gate voltage | 5 | V | | | |

Tables 4: Electrical Characteristics ($T_j = 25$ °C, unless otherwise specified)

| Symbol | Test Conditions | | Value | Unit | |
|------------------|-----------------------------------------------------------------|------------------------|--------|------|------|
| I _{GT} | | | MIN. | 8 | mA |
| 'GI | $V_D = 12 V$ $R_L = 33 \Omega$ | | MAX. | 80 | |
| V _{GT} | | | MAX. | 1.3 | V |
| V _{GD} | $V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ | T _j = 125°C | MIN. | 0.2 | V |
| I _H | I _T = 500 mA Gate open | | MAX. | 150 | mA |
| IL | $I_G = 1.2 \times I_{GT}$ | | MAX. | 200 | mA |
| dV/dt | $V_D = 67 \% V_{DRM}$ Gate open $T_j = 125$ °C | | MIN. | 1000 | V/µs |
| V _{TM} | $I_{TM} = 100 \text{ A}$ tp = 380 µs $T_j = 25^{\circ}\text{C}$ | | MAX. | 1.9 | V |
| V _{t0} | Threshold voltage $T_j = 125$ °C | | MAX. | 1.0 | V |
| R _d | Dynamic resistance $T_j = 125^{\circ}0$ | | MAX. | 8.5 | mΩ |
| I _{DRM} | $V_{DRM} = V_{RRM}$ | T _j = 25°C | MAX. | 10 | μΑ |
| I _{RRM} | TOHM - THHM | T _j = 125°C | IVIAA. | 5 | mA |

Table 5: Thermal resistance

| Symbol | Parameter | Value | Unit | |
|----------------------|----------------------------|------------------|------|------|
| R _{th(j-c)} | Junction to case (D.C.) | RD91 (Insulated) | 1.0 | °C/W |
| ' 'th(j-c) | duricular to case (b.c.) | TOP3 Insulated | 0.9 | 0/00 |
| R _{th(j-a)} | Junction to ambient (D.C.) | TOP3 Insulated | 50 | °C/W |

Figure 1: Maximum average power dissipation versus average on-state current

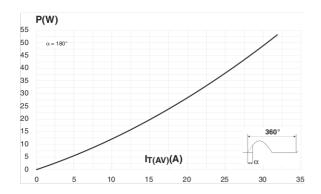
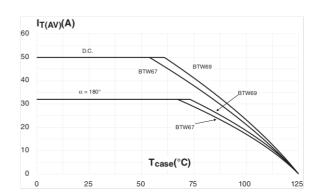


Figure 2: Average and D.C. on-state current versus case temperature



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Figure 3: Relative variation of thermal impedance versus pulse duration

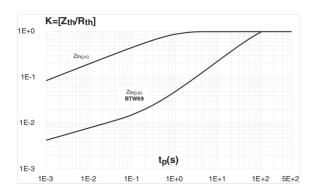


Figure 5: Surge peak on-state current versus number of cycles

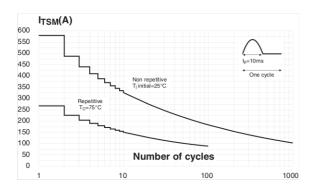


Figure 7: On-state characteristics (maximum values)

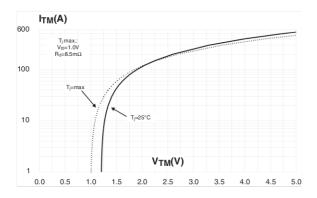


Figure 4: Relative variation of gate trigger current, holding current and latching current versus junction temperature

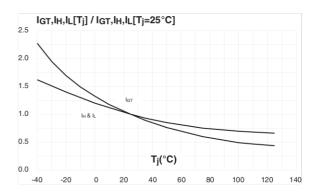
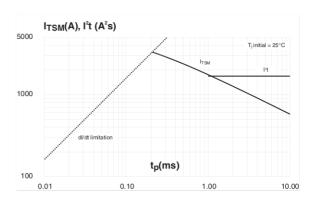


Figure 6: Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp < 10 ms, and corresponding values of I^2t



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Figure 8: Ordering Information Scheme

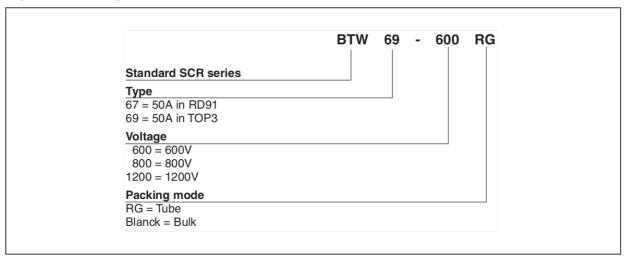
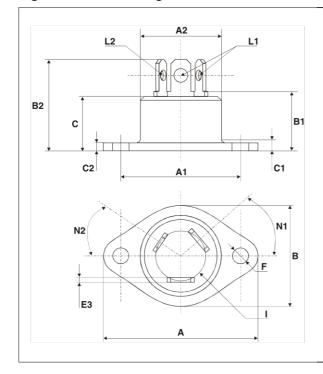


Table 6: Product Selector

| Part Numbers | | Voltage (xxx) | Sensitivity | Package | |
|--------------|--------------------|---------------|-------------|---------|-----------|
| rait Numbers | 600 V 800 V 1200 V | | Sensitivity | rackage | |
| BTW67-xxx | Х | Х | Х | 80 mA | RD91 |
| BTW69-xxx | Х | Х | Х | 80 mA | TOP3 Ins. |

Figure 9: RD91 Package Mechanical Data



| | | DIMENSIONS | | | | |
|------|--------|------------|-------|-------|--|--|
| REF. | Millin | neters | Inc | hes | | |
| | Min. | Max. | Min. | Max. | | |
| Α | | 40.00 | | 1.575 | | |
| A1 | 29.90 | 30.30 | 1.177 | 1.193 | | |
| A2 | | 22.00 | | 0.867 | | |
| В | | 27.00 | | 1.063 | | |
| B1 | 13.50 | 16.50 | 0.531 | 0.650 | | |
| B2 | | 24.00 | | 0.945 | | |
| С | | 14.00 | | 0.551 | | |
| C1 | | 3.50 | | 0.138 | | |
| C2 | 1.95 | 3.00 | 0.077 | 0.118 | | |
| E3 | 0.70 | 0.90 | 0.027 | 0.035 | | |
| F | 4.00 | 4.50 | 0.157 | 0.177 | | |
| I | 11.20 | 13.60 | 0.441 | 0.535 | | |
| L1 | 3.10 | 3.50 | 0.122 | 0.138 | | |
| L2 | 1.70 | 1.90 | 0.067 | 0.075 | | |
| N1 | 33° | 43° | 33° | 43° | | |
| N2 | 28° | 38° | 28° | 38° | | |

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Figure 10: TOP3 Insulated Package Mechanical Data

| | DIMENSIONS | | | | | |
|------|------------|------|------------|-------|-------|-------|
| REF. | Millimete | | ers Inches | | | |
| | Min. | Тур. | Max. | Min. | Тур. | Max. |
| Α | 4.4 | | 4.6 | 0.173 | | 0.181 |
| В | 1.45 | | 1.55 | 0.057 | | 0.061 |
| С | 14.35 | | 15.60 | 0.565 | | 0.614 |
| D | 0.5 | | 0.7 | 0.020 | | 0.028 |
| Е | 2.7 | | 2.9 | 0.106 | | 0.114 |
| F | 15.8 | | 16.5 | 0.622 | | 0.650 |
| G | 20.4 | | 21.1 | 0.815 | | 0.831 |
| Н | 15.1 | | 15.5 | 0.594 | | 0.610 |
| J | 5.4 | | 5.65 | 0.213 | | 0.222 |
| K | 3.4 | | 3.65 | 0.134 | | 0.144 |
| ØL | 4.08 | | 4.17 | 0.161 | | 0.164 |
| Р | 1.20 | | 1.40 | 0.047 | | 0.055 |
| R | | 4.60 | | | 0.181 | |

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Table 7: Ordering Information

| Ordering type | Marking | Package | Weight | Base qty | Delivery mode |
|---------------|----------|-----------|--------|----------|---------------|
| BTW67-xxx | BTW67xxx | RD91 | 20 g | 25 | Bulk |
| BTW69-xxxRG | BTW69xxx | TOP3 Ins. | 4.5 g | 30 | Tube |

Note: xxx = voltage

Table 8: Revision History

| Date | Revision | Description of Changes |
|-------------|----------|----------------------------------------------------------------------------------|
| Apr-2001 | 4A | Last update. |
| 13-Feb-2006 | 5 | TOP3 Insulated delivery mode changed from bulk to tube. ECOPACK statement added. |

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